

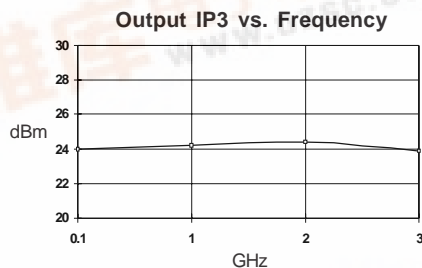


Product Description

Stanford Microdevices' SCA-7 is a high performance Gallium Arsenide Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration is utilized for broadband performance up to 3 GHz. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Typical IP3 at 40mA is +24dBm.

These unconditionally stable amplifiers provides 21dB of gain and +12dBm of 1dB compressed power and requires only a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional inductor are needed for operation.

This MMIC is an ideal choice for wireless applications such as cellular, PCS, CDPD, wireless data and SONET.



Electrical Specifications at Ta = 25C

Symbol	Parameters: Test Conditions: Id = 40mA, Z _o = 50 Ohms		Units	Min.	Typ.	Max.
G _P	Power Gain	f = 0.1-2.0 GHz f = 2.0-3.0 GHz	dB dB	18	20 18	
G _F	Gain Flatness Gain Flatness over any 100 MHz band	f = 0.1-2.0 GHz	dB dB		+/- 1.2 +/- 0.1	
P _{1dB}	Output Power at 1dB Compression:	f = 0.1-2.0 GHz	dBm		12.0	
NF	Noise Figure	f = 0.1-3.0 GHz	dB		3.8	
IP ₃	Third Order Intercept Point Output Tone @ 0dBm 10 MHz Apart	f = 0.1-2.0 GHz	dBm	23.0	24.0	
T _D	Group Delay	f = 1.9 GHz	psec		100	
ISOL	Reverse Isolation	f = 0.1-3.0 GHz	dB		22	
VD	Device Voltage		V	3.5	4.0	4.5
dG/dT	Device Gain Temperature Coefficient		dB/degC		-0.003	
dV/dT	Device Voltage Temperature Coefficient		mV/degC		-4.0	

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522 Almaden Ave., Sunnyvale, CA 94086

Phone: (800) SMI-MMIC

<http://www.stanfordmicro.com>

SCA-7

DC-3 GHz, Cascadable GaAs HBT MMIC Amplifier



Product Features

- High Output IP3 : +24dBm
- High Gain : Up to 21dB
- Cascadable 50 Ohm : 1.5:1 VSWR
- Patented GaAs HBT Technology
- Operates From Single Supply
- Low Thermal Resistance Package

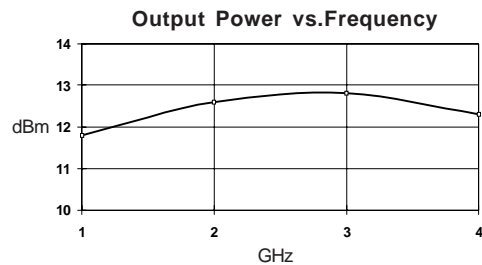
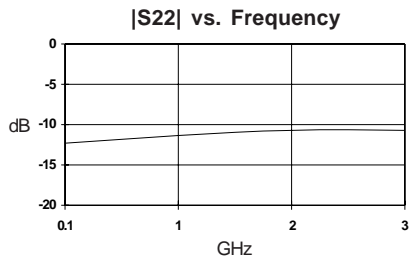
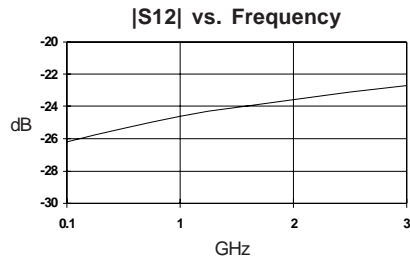
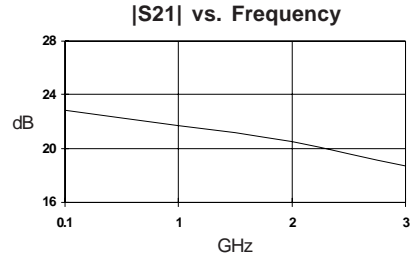
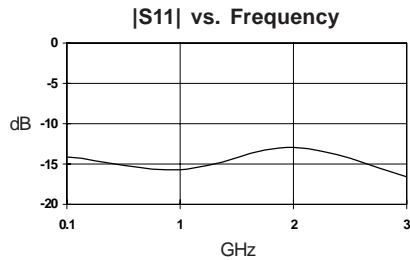
Applications

- Cellular, PCS, CDPD
- Wireless Data, SONET



SCA-7 DC-3 GHz Cascadable MMIC Amplifier

Typical Performance at 25° C ($V_{ds} = 4.0V$, $I_{ds} = 40mA$)



Typical S-Parameters $V_{ds} = 4.0V$, $I_d = 40mA$

Freq GHz	S11	S11 Ang	S21	S21 Ang	S12	S12 Ang	S22	S22 Ang
.100	0.338	117	13.126	139	0.064	-19	0.326	118
.500	0.322	112	13.096	130	0.056	-25	0.317	113
.900	0.310	61	12.333	93	0.057	-46	0.320	64
1.00	0.305	47	12.165	83	0.059	-50	0.320	51
1.50	0.271	-13	11.356	38	0.062	-79	0.316	-9
2.00	0.225	-71	10.626	-7	0.066	-107	0.307	-67
2.50	0.179	-129	9.175	-52	0.070	-138	0.298	-126
3.00	0.148	172	8.363	-90	0.073	-173	0.291	177

(S-Parameters include the effects of two 1.0 mil diameter bond wires, each 20 mils long, connected to the gate and drain pads on the die)

